



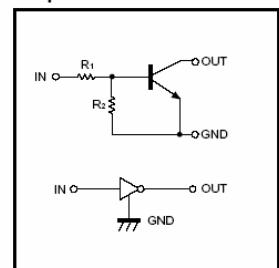
DTC114YE/DTC114YUA/DTC114YKA/DTC114YSA/DTC114YCA

DIGITAL TRANSISTOR (NPN)

FEATURES

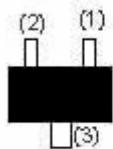
1. Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
2. The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
3. Only the on/off conditions need to be set for operation, making device design easy.

● Equivalent circuit



PIN CONNECTIONS AND MARKING

DTC114YE

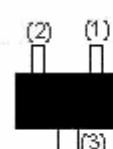


1.IN
2.GND
3.OUT

SOT-523

Addreviated symbol: 64

DTC114YUA

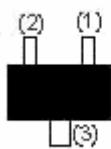


1.IN
2.GND
3.OUT

SOT-323

Addreviated symbol: 64

DTC114YKA

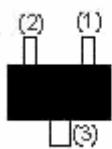


1.IN
2.GND
3.OUT

SOT-23-3L

Addreviated symbol: 64

DTC114YCA

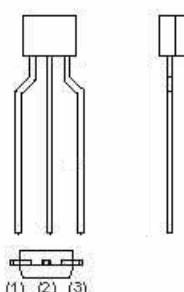


1.IN
2.GND
3.OUT

SOT-23

Addreviated symbol: 64

DTC114YSA



1.GND
2.OUT
3.IN

TO-92S



DTC114YE/DTC114YUA/DTC114YKA/DTC114YSA/DTC114YCA

Absolute maximum ratings(Ta=25°C)

Parameter	Symbol	Limits (DTC114Y□)					Unit
		E	UA	KA	CA	SA	
Supply voltage	V _{CC}			50			V
Input voltage	V _{IN}			-6to+40			V
Output current	I _O			70			mA
	I _{C(Max.)}			100			mA
Power dissipation	P _C	150		200		300	mW
Junction temperature	T _j			150			°C
Storage temperature	T _{STG}			-55 to+ 150			°C

Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ	Max.	Unit	Conditions
Input voltage	V _{I(off)}			0.3	V	V _{CC} =5V ,I _O =100μA
	V _{I(on)}	1.4				V _O =0.3V ,I _O =1mA
Output voltage	V _{O(on)}			0.3	V	I _O /I _I =5mA/0.25mA
Input current	I _I			0.88	mA	V _I =5V
Output current	I _{O(off)}			0.5	μA	V _{CC} =50V ,V _I =0
DC current gain	G _I	68				V _O =5V ,I _O =5mA
Input resistance	R _I	7	10	13	KΩ	
Resistance ratio	R ₂ /R ₁	3.7	4.7	5.7		
Transition frequency	f _T		250		MHz	V _O =10V ,I _O =5mA,f=100MHz

Typical Characteristics

